



U74AHCT3G06

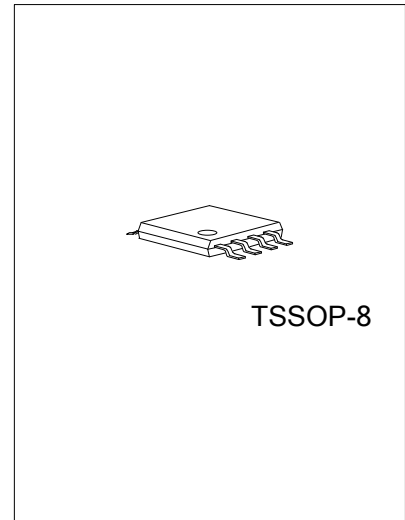
CMOS IC

INVERTER WITH OPEN-DRAIN OUTPUT

DESCRIPTION

The **U74AHCT3G06** is a high-speed Si-gate CMOS device which provides three inverting buffers with open-drain outputs. For digital operation this device must have a pull-up resistor to establish a logic HIGH-level.

The **U74AHCT3G06** is compatible of TTL input switching levels and has supply voltage range from 4.5V to 5.5V.



FEATURES

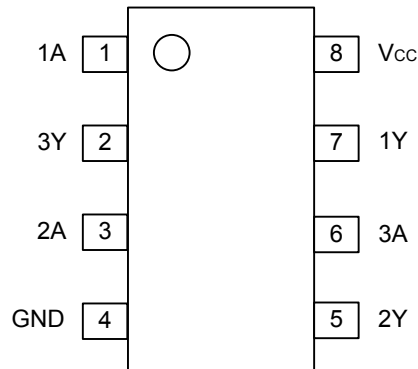
- * Low power supply 1.0µA at 5.5V
- * Up to 5.5V inputs accept voltages
- * Low power dissipation
- * Balanced propagation delays
- * High noise immunity
- * Output capability standard (open drain)

ORDERING INFORMATION

Ordering Number		Package	Packing
Lead Free	Halogen Free		
U74AHCT3G06L-P08-R	U74AHCT3G06G-P08-R	TSSOP-8	Tape Reel
U74AHCT3G06L-P08-T	U74AHCT3G06G-P08-T	TSSOP-8	Tube

<p>U74AHCT3G06L-P08-R</p>	<p>(1)Packing Type (2)Package Type (3)Lead Free</p>	<p>(1) R: Tape Reel, T: Tube (2) P08: TSSOP-8 (3) G: Halogen Free, L: Lead Free</p>
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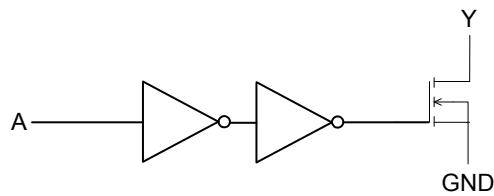
■ PIN CONFIGURATION



■ FUNCTION TABLE (each gate)

INPUT(A)	OUTPUT(Y)
L	Z
H	L

■ LOGIC DIAGRAM (each gate)



■ ABSOLUTE MAXIMUM RATING (unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V_{CC}	-0.5 ~ 7.0	V
Input Voltage	V_{IN}	-0.5 ~ 7.0	V
Output Voltage	V_{OUT}	-0.5 ~ 7.0(active mode)	V
Output Voltage		-0.5 ~ 7.0(high-impedance mode)	V
V_{CC} or GND Current	I_{CC}	±75	mA
Output Current	I_{OUT}	±25	mA
Input Clamp Current	I_{IK}	-20	mA
Output Clamp Current	I_{OUT}	±20	mA
Operating Temperature	T_{OPR}	-40 ~ + 85	
Storage Temperature	T_{STG}	-65 ~ + 150	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.
 Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V_{CC}		4.5	5.0	5.5	V
Input Voltage	V_{IN}		0		5.5	V
Output Voltage	V_{OUT}	Active mode	0		V_{CC}	V
		High-impedance mode	0		6.0	V
Input Rise or Fall Times	t_R, t_F	$V_{CC} = 5.0 \pm 0.5V$			20	ns/V

■ ELECTRICAL CHARACTERISTICS($T_A=25$)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
High-Level Input Voltage	V_{IH}	$V_{CC} = 4.5 V$ to $5.5 V$	2.0			V	
Low-Level Input Voltage	V_{IL}	$V_{CC} = 4.5 V$ to $5.5 V$			0.8	V	
Low-Level Output Voltage	V_{OL}	$V_{CC} = 4.5V,$ $V_I = V_{IH}$ or V_{IL}	$I_O = 50 \mu A$		0	0.1	V
			$I_O = 8.0 mA$			0.36	
Input Leakage Current	$I_{I(LEAK)}$	$V_I = 5.5V$ or GND, $V_{CC} = 0V$ to $5.5V$			0.1	μA	
3-State output OFF-State Current	I_{OZ}	$V_{CC} = 5.5V, V_I = V_{IH}$ or $V_{IL}, V_O = V_{CC}$ or GND			±.025	μA	
Quiescent Supply Current	I_{CC}	$V_{CC} = 5.5V, V_I = V_{CC}$ or GND, $I_O = 0$			1.0	μA	
Additional Quiescent Supply Current	ΔI_{CC}	$V_{CC} = 5.5V,$ One input at $3.4V,$ Other inputs at V_{CC} or GND, $I_{OUT} = 0$			1.35	mA	
Input Capacitance	C_{IN}	$V_I = V_{CC}$ or GND		1.5	10	pF	

■ SWITCHING CHARACTERISTICS ($T_A=25^\circ\text{C}$, $t_R = t_F \leq 3.0\text{ ns}$)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Propagation Delay from Input (A) to Output(Y)	t_{PZL}	$V_{CC} 4.5V\text{ to }5.5V$	$C_L 15pF$	-	3.0	5.3	ns
	t_{PLZ}			-	3.2	4.6	
	t_{PZL}		$C_L 50pF$	-	4.2	7.5	ns
	t_{PLZ}			-	4.5	7.0	

■ OPERATING CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

PARAMETER	SYMBOL	TEST CONDITIONS	TYP	UNIT
Power Dissipation Capacitance	C_{PD}	$C_L=50pF, f=1MHz$ (Note1, 2)	4.5	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o)$$

where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

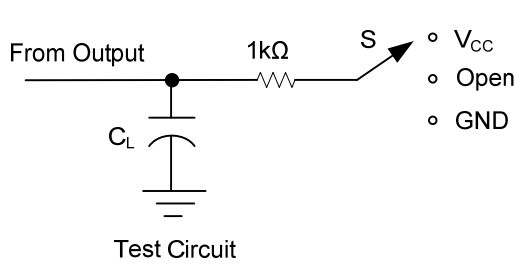
V_{CC} = supply voltage in Volts;

N = number of inputs switching;

$\sum(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

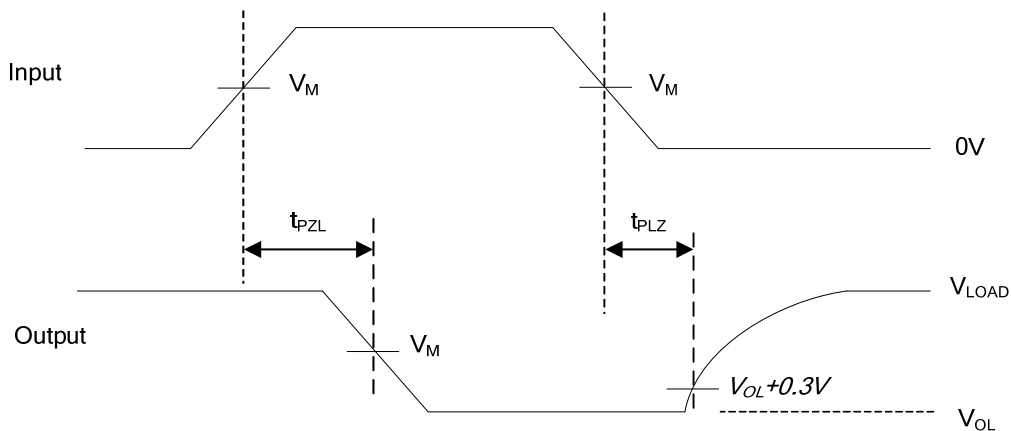
2. The condition is $V_I = GND$ to V_{CC} .

TEST CIRCUIT AND WAVEFORMS



TEST	S
t_{PLH}/t_{PHL}	Open
t_{PHZ}/t_{PZH}	GND
t_{PLZ}/t_{PZL}	V_{CC}

V_I	V_M	V_M
GND to V_{CC}	$50\%V_{CC}$	$50\%V_{CC}$



Voltage Waveforms Enable and Disable Times

Note: C_L includes probe and jig capacitance.
 $P_{RR} \leq 1MHz$, $Z_O = 50\Omega$, $t_R \leq 3ns$, $t_F \leq 3ns$.

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